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June 2002 Revised March 2004

FAIRCHILD

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NC7SP125 TinyLogic® ULP Buffer with 3-STATE Output

General Description

The NC7SP125 is a single Buffer with 3-STATE output from Fairchild's Ultra Low Power (ULP) series of TinyLogic®. Ideal for applications where battery life is critical, this product is designed for ultra low power consumption within the $\rm V_{CC}$ operating range of 0.9V to 3.6V.

The internal circuit is composed of a minimum of inverter stages, including the output buffer, to enable ultra low static and dynamic power.

The NC7SP125, for lower drive requirements, is uniquely designed for optimized power and speed, and is fabricated with an advanced CMOS technology to achieve best in class speed operation while maintaining extremely low CMOS power dissipation.

Features

- 0.9V to 3.6V V_{CC} supply operation
- 3.6V overvoltage tolerant I/O's at V_{CC} from 0.9V to 3.6V

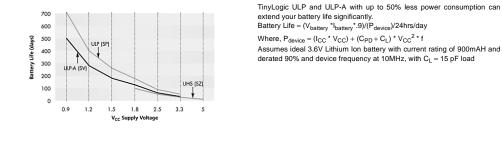
■ t_{PD}

- 3 ns typ for 3.0V to 3.6V V_{CC}
- 4 ns typ for 2.3V to 2.7V V_{CC}
- 5 ns typ for 1.65V to 1.95V V_{CC}
- 6 ns typ for 1.40V to 1.60V V_{CC}
- 10 ns typ for 1.10V to 1.30V V_{CC}
- 26 ns typ for 0.90V V_{CC}
- Power-Off high impedance inputs and outputs
- Static Drive (I_{OH}/I_{OL}) ±2.6 mA @ 3.00V V_{CC} ±2.1 mA @ 2.30V V_{CC} ±1.5 mA @ 1.65V V_{CC} ±1.0 mA @ 1.40V V_{CC} ±0.5 mA @ 1.10V V_{CC}
 - $\pm 20~\mu A$ $@~0.9V~V_{CC}$
- Uses patented Quiet Series[™] noise/EMI reduction circuitry
- Ultra small MicroPak[™] leadfree packages
- Ultra low dynamic power

Ordering Code:

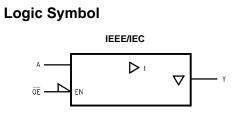
Order Number	Package Number	Product Code Top Mark	Package Description	Supplied As
NC7SP125P5X	MAA05A	P25	5-Lead SC70, EIAJ SC-88a, 1.25mm Wide	3k Units on Tape and Reel
NC7SP125L6X	MAC06A	L5	6-Lead MicroPak, 1.0mm Wide	5k Units on Tape and Reel

Battery Life vs. V_{CC} Supply Voltage



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Pin Descriptions

Pin Names	Description
A, OE	Input
Y	Output
NC	No Connect

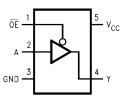
Function Table

Inp	out	Output
OE	In A	Out Y
L	L	L
L	н	н
Н	Х	Z

H = HIGH Logic Level L = LOW Logic Level X = HIGH or LOW Logic Level Z = HIGH Impedance State

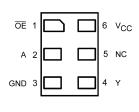
Connection Diagrams

Pin Assignments for SC70



(Top View)

Pad Assignments for MicroPak



(Top Thru View)

Absolute Maximum Rati	NgS (Note 1)	Recommended Operating	9
Supply Voltage (V _{CC})	-0.5V to +4.6V	Conditions (Note 3)	
DC Input Voltage (VIN)	-0.5V to +4.6V	Supply Voltage	0.9V to 3.6V
DC Output Voltage (V _{OUT})		Input Voltage (V _{IN})	0V to 3.6V
HIGH or LOW State (Note 2)	–0.5V to V _{CC} +0.5V	Output Voltage (V _{OUT})	
$V_{CC} = 0V$	-0.5V to 4.6V	HIGH or LOW State	0V to V_{CC}
DC Input Diode Current (I _{IK}) $V_{IN} < 0V$	±50 mA	$V_{CC} = 0V$	0V to 3.6V
DC Output Diode Current (I _{OK})		Output Current in I _{OH} /I _{OL}	
V _{OUT} < 0V	–50 mA	$V_{CC} = 3.0V$ to $3.6V$	±2.6 mA
V _{OUT} > V _{CC}	+50 mA	$V_{CC} = 2.3V$ to 2.7V	± 2.1 mA
DC Output Source/Sink Current (I _{OH} /I _{OL})	\pm 50 mA	V _{CC} = 1.65V to 1.95V	± 1.5 mA
DC V _{CC} or Ground Current per		V _{CC} = 1.40V to 1.60V	± 1 mA
Supply Pin (I _{CC} or Ground)	\pm 50 mA	V _{CC} = 1.10V to 1.30V	±0.5 mA
Storage Temperature Range (T _{STG})	$-65^{\circ}C$ to $+150^{\circ}C$	$V_{CC} = 0.9V$	±20 μA
		Free Air Operating Temperature (T ₄)	-40°C to +85°C

-40°C to +85°C Free Air Operating Temperature (T_A) Minimum Input Edge Rate ($\Delta t/\Delta V$) V_{IN} = 0.8V to 2.0V, V_{CC} = 3.0V 10 ns/V Note 1: Absolute Maximum Ratings: are those values beyond which the

safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: I_{O} Absolute Maximum Rating must be observed.

Note 3: Unused inputs must be held HIGH or LOW. They may not float.

Units

V

Conditions

Symbol	Parameter	V _{cc}	TA = -	+25°C	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		
Gymbol	ranameter	(V)	Min	Max	Min	Max	
V _{IH}	HIGH Level	0.90	0.65 x V _{CC}		0.65 x V _{CC}		
	Input Voltage	$1.10 \leq V_{CC} \leq 1.30$	$0.65 \times V_{CC}$		$0.65 \times V_{CC}$		
		$1.40 \leq V_{CC} \leq 1.60$	$0.65 \times V_{CC}$		$0.65 \times V_{CC}$		
		$\begin{split} 1.10 &\leq V_{CC} \leq 1.30 \\ 1.40 &\leq V_{CC} \leq 1.60 \\ 1.65 &\leq V_{CC} \leq 1.95 \\ 2.30 &\leq V_{CC} \leq 2.70 \end{split}$	$0.65 \times V_{CC}$		$0.65 \times V_{CC}$		
		$2.30 \leq V_{CC} \leq 2.70$	1.6		1.6		
		$3.00 \leq V_{CC} \leq 3.60$	2.1		2.1		
VIL	LOW Level	0.90		0.35 x V _{CC}		0.35 x V _{CC}	

DC Electrical Characteristics

.6 2.1 0.35 x V_{CC} 0.35 x V_{CC} LOW Level 0.90 0.35 x V_{CC} $1.10 \leq V_{CC} \leq 1.30$ $0.35 \times V_{CC}$ Input Voltage $0.35 \times V_{CC}$ $0.35 \times V_{CC}$ $1.40 \leq V_{CC} \leq 1.60$ V 0.35 x V_{CC} $1.65 \leq V_{CC} \leq 1.95$ $0.35 \times V_{CC}$ $2.30 \leq V_{CC} \leq 2.70$ 0.7 0.7 $3.00 \leq V_{CC} \leq 3.60$ 0.9 0.9 HIGH Level 0.90 $V_{CC} - 0.1$ $V_{CC} - 0.1$ V_{ОН} Output Voltage $V_{CC} - 0.1$ $V_{CC} - 0.1$ $1.10 \leq V_{CC} \leq 1.30$ $V_{CC} - 0.1$ V_{CC} - 0.1 $1.40 \le V_{CC} \le 1.60$ $I_{OH} = -20 \ \mu A$ $1.65 \leq V_{CC} \leq 1.95$ $V_{CC} - 0.1$ $V_{CC} - 0.1$ $2.30 \leq V_{CC} \leq 2.70$ $V_{CC}-0.1$ $V_{CC} - 0.1$ V_{CC} - 0.1 V_{CC} - 0.1 $3.00 \leq V_{CC} \leq 3.60$ V $I_{OH} = -0.5 \text{ mA}$ 0.70 x V_{CC} $1.10 \leq V_{CC} \leq 1.30$ 0.75 x V_{CC} $1.40 \leq V_{CC} \leq 1.60$ 1.07 0.99 $I_{OH} = -1 \text{ mA}$ $1.65 \leq V_{CC} \leq 1.95$ 1.24 1.22 I_{OH} = -1.5 mA $I_{OH} = -2.1 \text{ mA}$ $2.30 \leq V_{CC} \leq 2.70$ 1.95 1.87 $I_{OH} = -2.6 \text{ mA}$ $3.00 \leq V_{CC} \leq 3.60$ 2.61 2.55

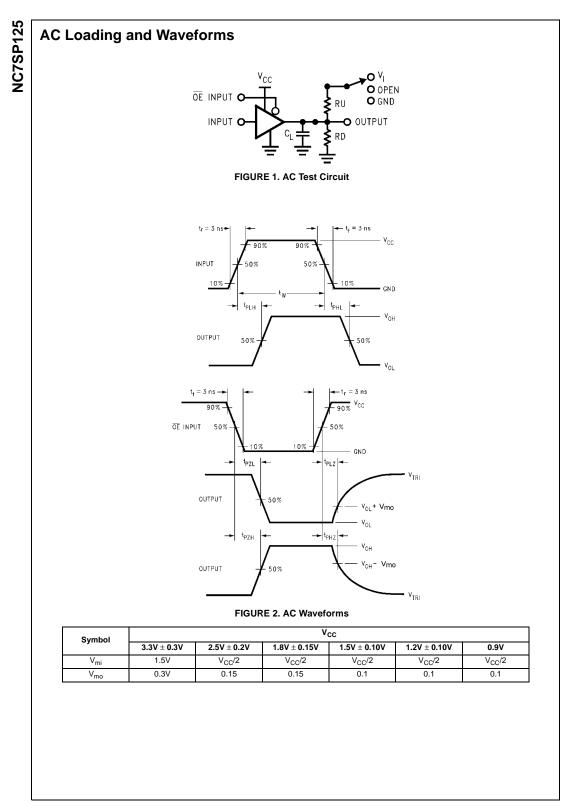
DC Electrical Characteristics (Continued)

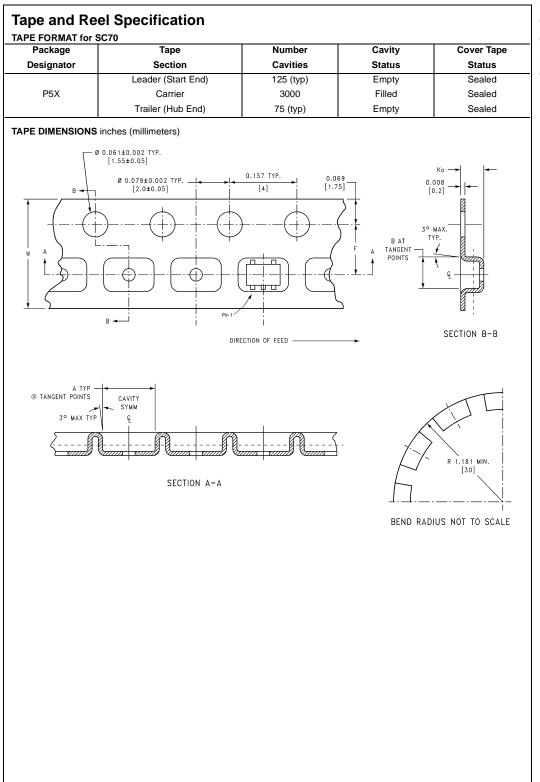
Symbol	Parameter	V _{cc}	T _A = +25°C		$T_{A} = -40^{\circ}$	C to +85°C	Units	Conditions	
Symbol	Farameter	(V)	Min	Min Max		Min Max		Conditions	
V _{OL}	LOW Level	0.90		0.1		0.1			
	Output Voltage	$1.10 \leq V_{CC} \leq 1.30$		0.1		0.1			
		$1.40 \leq V_{CC} \leq 1.60$		0.1		0.1		L = 20 A	
		$1.65 \leq V_{CC} \leq 1.95$		0.1		0.1		$I_{OL} = 20 \ \mu A$	
		$2.30 \leq V_{CC} \leq 2.70$		0.1		0.1			
		$3.00 \leq V_{CC} \leq 3.60$		0.1		0.1	V		
		$1.10 \leq V_{CC} \leq 1.30$	0	.30 x V _{CC}		$0.30 \times V_{CC}$		I _{OL} = 0.5 mA	
		$1.40 \leq V_{CC} \leq 1.60$		0.31		0.37		I _{OL} = 1 mA	
		$1.65 \leq V_{CC} \leq 1.95$		0.31		0.35		I _{OL} = 1.5 mA	
		$2.30 \leq V_{CC} \leq 2.70$		0.31		0.33		I _{OL} = 2.1 mA	
		$3.00 \leq V_{CC} \leq 3.60$		0.31		0.33		I _{OL} = 2.6 mA	
I _{IN}	Input Leakage Current	0.90 to 3.60		±0.1		±0.5	μA	$0 \le V_I \le 3.6V$	
I _{OZ}	3-STATE Output	0.90 to 3.60		+0 E		±0.5		$V_I = V_{IH} \text{ or } V_{IL}$	
	Leakage	0.90 10 3.60		±0.5		±0.5	μA	$0 \leq V_O \leq 3.6V$	
I _{OFF}	Power Off Leakage Current	0		0.5		0.5	μA	$0 \leq (V_I, V_O) \leq 3.6V$	
I _{CC}	Quiescent Supply Current	0.90 to 3.60		0.9		0.9	μA	$V_I = V_{CC}$ or GND	

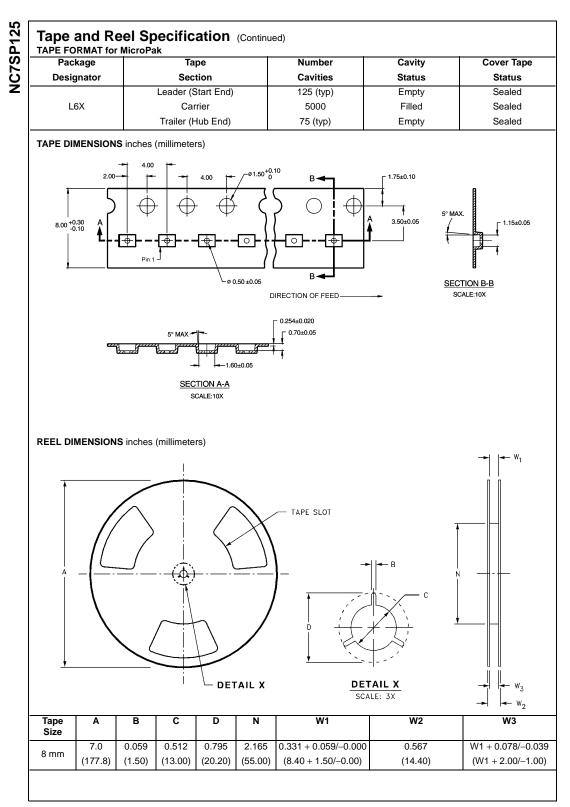
AC Electrical Characteristics

Symbol	Parameter	V _{cc}		T _A = +25°C	;	$\textbf{T}_{\textbf{A}}=-40^{\circ}\textbf{C} \text{ to }+85^{\circ}\textbf{C}$		Units	Conditions	Figure
Symbol	Farameter	(V)	Min	Тур	Max	Min	Max	Units	Conditions	Numbe
t _{PHL}	Propagation Delay	0.90		26						
t _{PLH}		$1.10 \leq V_{CC} \leq 1.30$	4.0	10	19.1	3.5	39.6			
		$1.40 \leq V_{CC} \leq 1.60$	2.0	6	11.2	1.5	14.5	ns	C _L = 10 pF	
		$1.65 \leq V_{CC} \leq 1.95$	1.5	5	8.6	1.0	11.6	ns	$R_L = 1 M\Omega$	
		$2.30 \leq V_{CC} \leq 2.70$	1.0	4	6.3	0.8	8.2			
		$3.00 \leq V_{CC} \leq 3.60$	1.0	3	5.3	0.5	7.2			
PZH	Output	0.90		29					C _L = 10 pF	
PZL	Enable Time	$1.10 \leq V_{CC} \leq 1.30$	4.0	8	17.5	3.5	40.4		$R_U = 5000\Omega$	
		$1.40 \leq V_{CC} \leq 1.60$	2.0	6	11.9	1.5	14.8		$R_D = 5000\Omega$	
		$1.65 \leq V_{CC} \leq 1.95$	1.5	5	9.7	1.0	12.3	ns	$S_1 = GND$ for t_{PZH}	
		$2.30 \leq V_{CC} \leq 2.70$	1.0	4	7.7	0.8	10.5		$S_1 = V_I$ for t_{PZL}	
		$3.00 \leq V_{CC} \leq 3.60$	1.0	3	6.9	0.5	8.6		$V_I = 2 \times V_{CC}$	
PHZ	Output	0.90		28					C _L = 10 pF	
PLZ	Disable Time	$1.10 \leq V_{CC} \leq 1.30$	4.0	8	20.5	3.5	42.0		$R_U = 5000 \Omega$	
		$1.40 \leq V_{CC} \leq 1.60$	2.0	6	15.3	1.5	18.0		$R_D = 5000\Omega$	
		$1.65 \leq V_{CC} \leq 1.95$	1.5	5	14.7	1.0	17.8	ns	$S_1 = GND$ for t_{PHZ}	
		$2.30 \leq V_{CC} \leq 2.70$	1.0	4	13.7	0.8	15.0		$S_1 = V_I$ for t_{PLZ}	
		$3.00 \leq V_{CC} \leq 3.60$	1.0	3	13.5	0.5	14.8		$V_I = 2 \times V_{CC}$	
t _{PHL}	Propagation Delay	0.90		28						
t _{PLH}		$1.10 \leq V_{CC} \leq 1.30$	5.0	10	20.5	4.5	42.5			
		$1.40 \leq V_{CC} \leq 1.60$	3.0	7	11.8	2.5	15.4	ns	$C_L = 15 \text{ pF}$	Figure
		$1.65 \leq V_{CC} \leq 1.95$	2.0	5	9.1	2.0	12.2	115	$R_L = 1 \ M\Omega$	1, 2
		$2.30 \leq V_{CC} \leq 2.70$	1.5	4	6.6	1.0	8.6			
		$3.00 \leq V_{CC} \leq 3.60$	1.0	3	5.6	0.5	7.5			
t _{PZH}	Output	0.90		31					C _L = 15 pF	
PZL	Enable Time	$1.10 \leq V_{CC} \leq 1.30$	5.0	11	18.2	4.5	43.3		$R_U = 5000\Omega$	
		$1.40 \leq V_{CC} \leq 1.60$	3.0	7	12.5	2.5	15.5		$R_D = 5000\Omega$	Figure
		$1.65 \leq V_{CC} \leq 1.95$	2.0	5	10.2	2.0	12.9	ns	$S_1 = GND$ for t_{PZH}	1, 2
		$2.30 \leq V_{CC} \leq 2.70$	1.5	4	8.0	1.0	9.9		$S_1 = V_I \text{ for } t_{PLZ}$	
		$3.00 \leq V_{CC} \leq 3.60$	1.0	3	7.2	0.5	8.9		$V_1 = 2 \times V_{CC}$	

Symbol	Parameter	V _{CC}	$T_A = +25^{\circ}C$			$T_A = -40^{\circ}C$	$T_{A}=-40^{\circ}C$ to $+85^{\circ}C$		Conditions	Figure
Symbol	Parameter	(V)	Min	Тур	Max	Min	Max	Units	Conditions	Number
t _{PHZ}	Output	0.90		30					$C_L = 15 \text{ pF}$	
t _{PLZ}	Disable Time	$1.10 \leq V_{CC} \leq 1.30$	5.0	11	21.6	4.5	44.9		$R_U = 5000\Omega$	
		$1.40 \leq V_{CC} \leq 1.60$	3.0	7	15.9	2.5	18.8	ns	$R_D = 5000\Omega$	Figures
		$1.65 \leq V_{CC} \leq 1.95$	2.0	5	15.2	2.0	18.2	115	$S_1 = GND$ for t_{PHZ}	1, 2
		$2.30 \leq V_{CC} \leq 2.70$	1.5	4	14.1	1.0	15.4		$S_1 = V_I$ for t_{PLZ}	
		$3.00 \leq V_{CC} \leq 3.60$	1.0	3	13.9	0.5	15.1		$V_1 = 2 \times V_{CC}$	
t _{PHL}	Propagation Delay	0.90		34						
t _{PLH}		$1.10 \leq V_{CC} \leq 1.30$	5.5	12	23.4	5.0	51.1			
		$1.40 \leq V_{CC} \leq 1.60$	4.0	8	13.8	3.0	17.7	ns	$C_L = 30 \ pF\Omega$	Figures
		$1.65 \leq V_{CC} \leq 1.95$	2.0	6	10.6	2.0	14.0	115	$R_L = 1M\Omega$	1, 2
		$2.30 \leq V_{CC} \leq 2.70$	1.0	5	7.6	1.0	9.9			
		$3.00 \leq V_{CC} \leq 3.60$	0.8	4	6.4	0.5	8.9			
t _{PZH}	Output	0.90		37					$C_L = 30 \text{ pF}$	
t _{PZL}	Enable Time	$1.10 \leq V_{CC} \leq 1.30$	6.0	13	24.4	5.0	51.9		$R_U = 5000\Omega$	
		$1.40 \leq V_{CC} \leq 1.60$	4.0	8	14.5	3.0	17.9	ns	$R_D = 5000\Omega$	Figures
		$1.65 \leq V_{CC} \leq 1.95$	2.0	6	11.7	2.0	14.7	113	$S_1 = GND \text{ for } t_{PZH}$	1, 2
		$2.30 \leq V_{CC} \leq 2.70$	1.0	5	9.1	1.0	11.1		$S_1 = V_I \text{ for } t_{PZL}$	
		$3.00 \leq V_{CC} \leq 3.60$	0.8	4	8.1	0.5	10.1		$V_I = 2 \times V_{CC}$	
t _{PHZ}	Output	0.90		36					$C_L = 30 \text{ pF}$	
t _{PLZ}	Disable Time	$1.10 \leq V_{CC} \leq 1.30$	6.0	13	24.8	5.0	53.5		$R_U = 5000\Omega$	
		$1.40 \leq V_{CC} \leq 1.60$	4.0	8	17.1	3.0	21.1	ns	$R_D = 5000\Omega$	Figures
		$1.65 \leq V_{CC} \leq 1.95$	2.0	6	16.5	2.0	20.5	110	$S_1 = GND \text{ for } t_{PHZ}$	1, 2
		$2.30 \leq V_{CC} \leq 2.70$	1.0	5	15.2	1.0	16.7		$S_1 = V_I \text{ for } t_{PLZ}$	
		$3.00 \leq V_{CC} \leq 3.60$	0.8	4	14.8	0.5	16.3		$V_I = 2 \times V_{CC}$	
CIN	Input Capacitance	0		2.0				pF		
C _{OUT}	Output Capacitance	0		4.0				pF		
C _{PD}	Power Dissipation Capacitance	0.9 to 3.60		8				pF	$V_I = 0V \text{ or } V_{CC},$ f = 10 MHz	







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